DECES



→A ←

BAS116V

SURFACE MOUNT LOW LEAKAGE DIODE

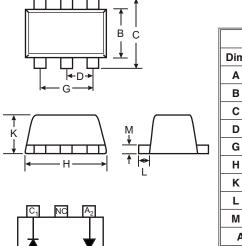
Features

Surface Mount Package Ideally Suited for Automatic Insertion Very Low Leakage Current

Lead Free By Design/RoHS Compliant (Note 1)

Mechanical Data

Case: SOT-563, Molded Plastic Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0 Moisture Sensitivity: Level 1 per J-STD-020C Terminal Connections: See Diagram Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208 Marking & Type Code Information: See Last Page Ordering Information: See Last Page Weight: 0.003 grams (approximate)



SOT-563									
Dim	Min	Max	Тур						
Α	0.15	0.30	0.25						
В	1.10	1.25	1.20						
С	1.55	1.70	1.60						
D	0.50								
G	0.90	1.10	1.00						
Н	1.50	1.70	1.60						
к	0.56	0.60	0.60						
L	0.10	0.30	0.20						
М	0.10	0.18	0.11						
All	All Dimensions in mm								

Maximum Ratings @ $T_A = 25$ C unless otherwise specified

Characteristic	Symbol	Value	Unit		
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	85	V	
RMS Reverse Voltage	V _{R(RMS)}	60	V		
Forward Continuous Current (Note 2)	I _{FM}	215	mA		
Repetitive Peak Forward Current	I _{FRM}	500	mA		
	2 t = 1.0 s 2 t = 1.0ms 2 t = 1.0s	I _{FSM}	4.0 1.0 0.5	A	
Operating and Storage Temperature Range		T_{j} , T_{STG}	-65 to +150	С	

NC

Thermal Characteristics @ T_A = 25 C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 2)	Pd	150	mW	
Thermal Resistance Junction to Ambient Air (Note 2)	R ja	833	C/W	

Electrical Characteristics @ TA = 25 C unless otherwise specified

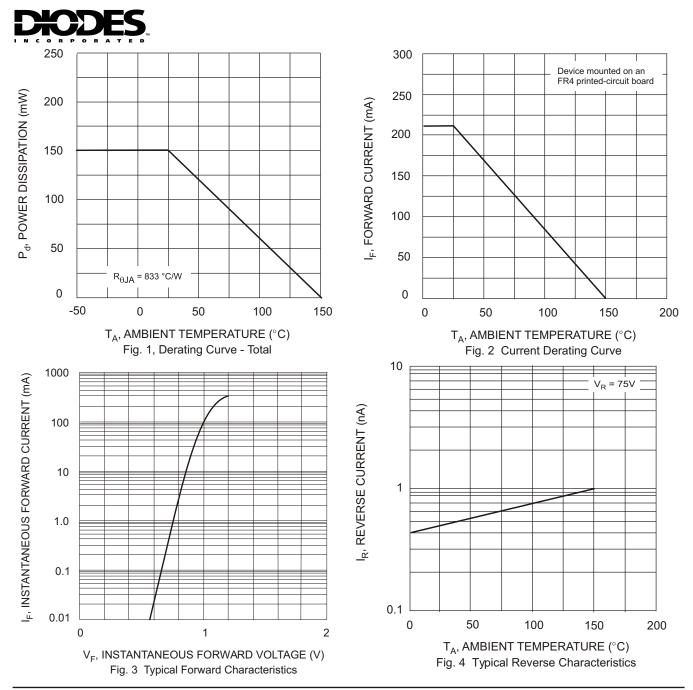
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
Reverse Breakdown Voltage (Note 3)	V _{(BR)R}	85			V	I _R = 100 A		
Forward Voltage	V _{FM}			0.90 1.0 1.1 1.25	V	$ \begin{array}{l} I_F = 1.0mA \\ I_F = 10mA \\ I_F = 50mA \\ I_F = 150mA \end{array} $		
Leakage Current (Note 3)	I _{RM}			5.0 80	nA nA	$V_R = 75V$ $V_R = 75V$, $T_j = 150$ C		
Total Capacitance	Ст		2		pF	V _R = 0, f = 1.0MHz		
Reverse Recovery Time	t _{rr}			3.0	s	$I_F = I_R = 10mA,$ $I_{rr} = 0.1 \times I_R, R_L = 100$		

Note: 1. No purposefully added lead.

2. Part mounted on FR-4 board with recommended pad layout, which can be found on our website

at http://www.diodes.com/datasheets/ap02001.pdf.

3. Short duration test pulse used to minimize self-heating effect.



Ordering Information (Note 4)

Device	Packaging	Shipping		
BAS116V-7	SOT-563	3000/Tape & Reel		

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



KAZ = Product Type Marking Code (See Page 1 Diagrams) YM = Date Code Marking Y = Year (ex: R = 2004)M = Month (ex: 9 = September)

Date Code Key

Year			2004	2005	2006	2007	2008	2009	2010	2011	2012	
Code			R	S	Т	U	V	W	Х	Y	Z	
Month	Jan	Feb	March	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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